AUTOMOTIVE GRADE

International Rectifier

Features

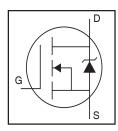
- Advanced Process Technology
- Ultra Low On-Resistance
- Dynamic dv/dt Rating
- 175°C Operating Temperature
- Fast Switching
- Repetitive Avalanche Allowed up to Timax
- Lead-Free, RoHS Compliant
- Automotive Qualified *

Description

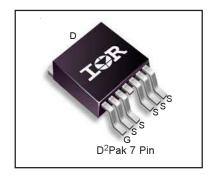
Specifically designed for Automotive applications, this HEXFET® Power MOSFET utilizes the latest processing techniques to achieve extremely low on-resistance per silicon area. Additional features of this design are a 175°C junction operating temperature, fast switching speed and improved repetitive avalanche rating. These features combine to make this design an extremely efficient and reliable device for use in Automotive applications and a wide variety of other applications.

AUIRFS3006-7P

HEXFET® Power MOSFET



V _{DSS}	60V
R _{DS(on)} typ.	1.5m Ω
max.	$2.1 m\Omega$
I _D (Silicon Limited)	293A ①
I _{D (Package Limited)}	240A



G	D	S
Gate	Drain	Source

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

Symbol	Parameter	Max.	Units
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V (Silicon Limited)	293①	
I _D @ T _C = 100°C	Continuous Drain Current, V _{GS} @ 10V (Silicon Limited)	207①	
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V (Package Limited)	240	A
I _{DM}	Pulsed Drain Current ②	1172	7
P _D @T _C = 25°C	Maximum Power Dissipation	375	W
	Linear Derating Factor	2.5	W/°C
V _{GS}	Gate-to-Source Voltage	± 20	V
E _{AS}	Single Pulse Avalanche Energy (Thermally Limited) 3	303	mJ
I _{AR}	Avalanche Current ②	See Fig. 14, 15, 22a, 22b,	Α
E _{AR}	Repetitive Avalanche Energy ②		mJ
dv/dt	Peak Diode Recovery 4	11	V/ns
T_J	Operating Junction and	-55 to + 175	
T _{STG}	Storage Temperature Range		→ °C
Soldering Temperature, for 10 seconds		300	
	(1.6mm from case)		

Thermal Resistance

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case ® ®		0.4	°C/W
$R_{\theta JA}$	Junction-to-Ambient (PCB Mount) ®		40	C/VV

HEXFET® is a registered trademark of International Rectifier.

^{*}Qualification standards can be found at http://www.irf.com/

Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source Breakdown Voltage	60			٧	$V_{GS} = 0V, I_{D} = 250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		0.07		V/°C	Reference to 25°C, I _D = 5mA ^②
R _{DS(on)}	Static Drain-to-Source On-Resistance		1.5	2.1	mΩ	V _{GS} = 10V, I _D = 168A ⑤
$V_{GS(th)}$	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
gfs	Forward Transconductance	290			S	$V_{DS} = 25V, I_{D} = 168A$
R _{G(int)}	Internal Gate Resistance		2.1		Ω	
I _{DSS}	Drain-to-Source Leakage Current			20		$V_{DS} = 60V$, $V_{GS} = 0V$
				250	μA	$V_{DS} = 60V, V_{GS} = 0V, T_{J} = 125^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage			100	π Λ	$V_{GS} = 20V$
	Gate-to-Source Reverse Leakage			-100	nA	$V_{GS} = -20V$

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	May	Units	Conditions
		IVIIII.				
Q_g	Total Gate Charge		200	300		I _D = 168A
Q_{gs}	Gate-to-Source Charge		37		nC	$V_{DS} = 30V$
Q_{gd}	Gate-to-Drain ("Miller") Charge		60		I IIC	V _{GS} = 10V ⑤
Q _{sync}	Total Gate Charge Sync. (Q _g - Q _{gd})		140			$I_D = 168A, V_{DS} = 0V, V_{GS} = 10V$
t _{d(on)}	Turn-On Delay Time		14			$V_{DD} = 39V$
t _r	Rise Time		61			I _D = 168A
t _{d(off)}	Turn-Off Delay Time		118		ns	$R_G = 2.7\Omega$
t _f	Fall Time		69			V _{GS} = 10V ⑤
C _{iss}	Input Capacitance		8850			$V_{GS} = 0V$
C _{oss}	Output Capacitance		1007			$V_{DS} = 50V$
C _{rss}	Reverse Transfer Capacitance		525		pF	f = 1.0MHz (See Fig 5)
C _{oss} eff. (ER)	Effective Output Capacitance (Energy Related)		1460		1	V _{GS} = 0V, V _{DS} = 0V to 48V ⑦(See Fig 11)
C _{oss} eff. (TR)	Effective Output Capacitance (Time Related) ©		1915			$V_{GS} = 0V, V_{DS} = 0V \text{ to } 48V $

Diode Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions
I _S	Continuous Source Current			2020		MOSFET symbol
	(Body Diode)			293 ^①		showing the
I _{SM}	Pulsed Source Current			1172	Α	integral reverse
	(Body Diode)			11/2		p-n junction diode.
V_{SD}	Diode Forward Voltage			1.3	٧	$T_J = 25^{\circ}C$, $I_S = 168A$, $V_{GS} = 0V$ \bigcirc
t _{rr}	Reverse Recovery Time		44		no	$T_{J} = 25^{\circ}C \qquad \qquad V_{R} = 51V,$
			48		ns	$T_J = 125^{\circ}C$ $I_F = 168A$
Q _{rr}	Reverse Recovery Charge		51		nC	$T_J = 25^{\circ}C$ di/dt = 100A/ μ s ©
			62			$T_J = 125$ °C
I _{RRM}	Reverse Recovery Current		2.03		Α	$T_J = 25^{\circ}C$
t _{on}	Forward Turn-On Time	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

- ① Calcuted continuous current based on maximum allowable junction temperature Bond wire current limit is 240A. Note that current limitation arising from heating of the device leds may occur with some lead mounting arrangements.
- ② Repetitive rating; pulse width limited by max. junction temperature.
- $\textcircled{1} \label{eq:loss_scale} I_{SD} \leq 168A, \ di/dt \leq 1410 \ A/\mu s, \ V_{DD} \leq V_{(BR)DSS}, \ T_J \leq 175^{\circ}C.$

- $\ \ \, \ \, \ \,$ $\ \ \, \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \$ $\$ $\ \$ $\$ $\$ $\ \$ $\$ $\$ $\$ $\$ $\ \$ $\$
- When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniquea refer to application note # AN-994 echniques refer to application note #AN-994.
- $\ \, \mathfrak{D} \, \, \, \mathsf{R}_{\theta \mathsf{JC}} \, \mathsf{value} \, \, \mathsf{shown} \, \, \mathsf{is} \, \, \mathsf{at} \, \, \mathsf{time} \, \, \mathsf{zero}.$

Qualification Information[†]

			Automotive ++				
			(per AEC-Q101) ^{††}				
Qualification Lev	el	qualification. IR	his part number(s) passed Automer's Industrial and Consumer qualification attension of the higher Automotive level.				
Moisture Sensitiv	ity Level	D ² Pak 7 Pin MSL1					
	Machine Model		Class M4 (+/- 800V) ^{†††}				
			AEC-Q101-002				
	Human Body Model		Class H3A (+/- 6000V) ^{†††}				
ESD	ESD		AEC-Q101-001				
Charged Device Model			Class C5 (+/- 2000V) ^{†††}				
			AEC-Q101-005				
RoHS Compliant	1		Yes				

[†] Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

^{††} Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.

^{†††} Highest passing voltage.

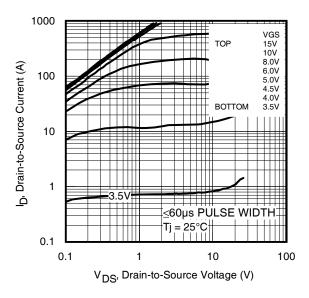


Fig 1. Typical Output Characteristics

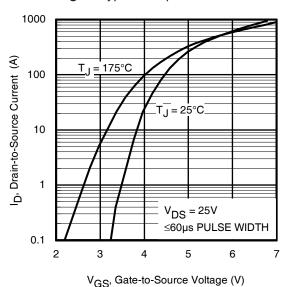


Fig 3. Typical Transfer Characteristics

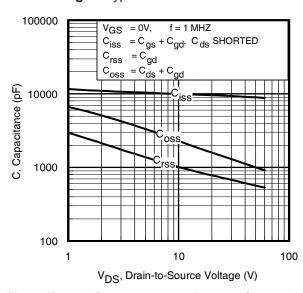


Fig 5. Typical Capacitance vs. Drain-to-Source Voltage

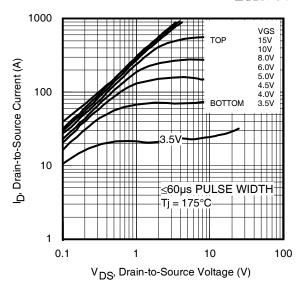


Fig 2. Typical Output Characteristics

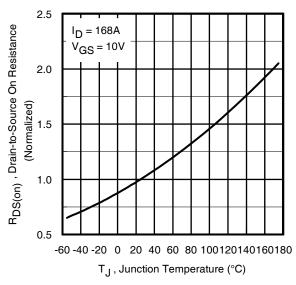


Fig 4. Normalized On-Resistance vs. Temperature

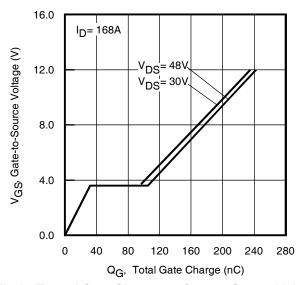


Fig 6. Typical Gate Charge vs. Gate-to-Source Voltage

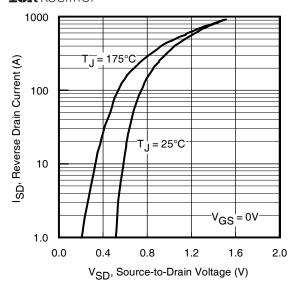


Fig 7. Typical Source-Drain Diode Forward Voltage

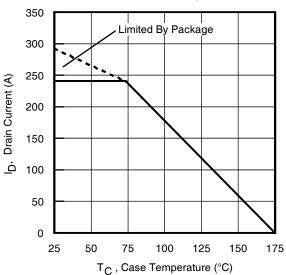
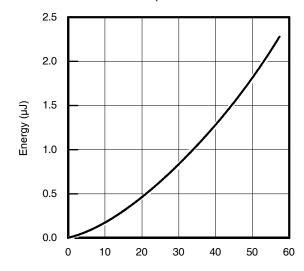


Fig 9. Maximum Drain Current vs.
Case Temperature



 $\label{eq:VDS} V_{DS,} \mbox{ Drain-to-Source Voltage (V)} \\ \mbox{\bf Fig 11. Typical C_{OSS} Stored Energy}$

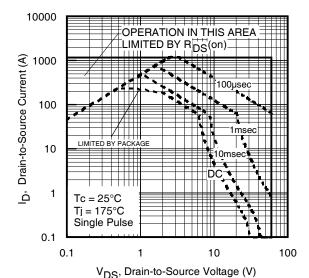


Fig 8. Maximum Safe Operating Area

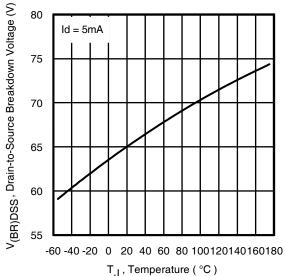


Fig 10. Drain-to-Source Breakdown Voltage

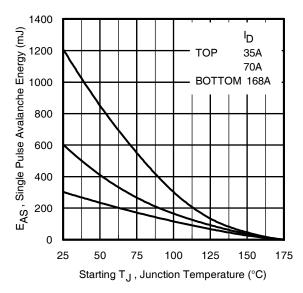


Fig 12. Maximum Avalanche Energy vs. DrainCurrent

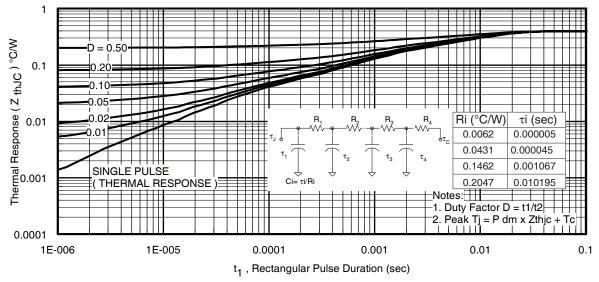


Fig 13. Maximum Effective Transient Thermal Impedance, Junction-to-Case

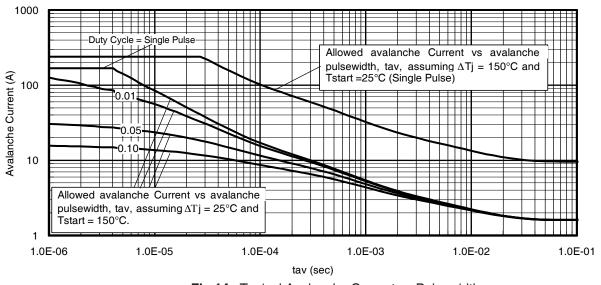


Fig 14. Typical Avalanche Current vs. Pulsewidth

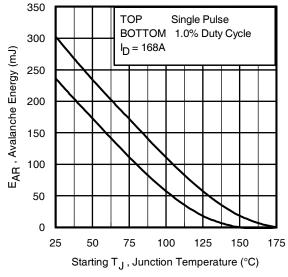


Fig 15. Maximum Avalanche Energy vs. Temperature

Notes on Repetitive Avalanche Curves , Figures 14, 15: (For further info, see AN-1005 at www.irf.com)

- 1. Avalanche failures assumption:
 - Purely a thermal phenomenon and failure occurs at a temperature far in excess of T_{jmax} . This is validated for every part type.
- 2. Safe operation in Avalanche is allowed as long asT_{imax} is not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 16a, 16b.
- 4. $P_{D (ave)}$ = Average power dissipation per single avalanche pulse.
- BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
- 6. I_{av} = Allowable avalanche current.
- 7. ΔT = Allowable rise in junction temperature, not to exceed T_{jmax} (assumed as 25°C in Figure 14, 15).

t_{av =} Average time in avalanche.

D = Duty cycle in avalanche = $t_{av} \cdot f$

 $Z_{th,JC}(D, t_{av})$ = Transient thermal resistance, see Figures 13)

$$\begin{split} P_{D \; (ave)} &= 1/2 \; (\; 1.3 \cdot BV \cdot I_{av}) = \triangle T / \; Z_{thJC} \\ I_{av} &= 2\triangle T / \; [1.3 \cdot BV \cdot Z_{th}] \\ E_{AS \; (AR)} &= P_{D \; (ave)} \cdot t_{av} \end{split}$$

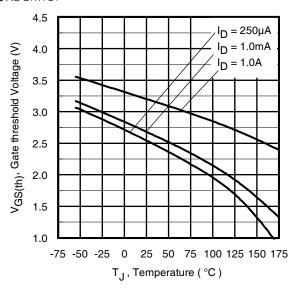


Fig 16. Threshold Voltage vs. Temperature

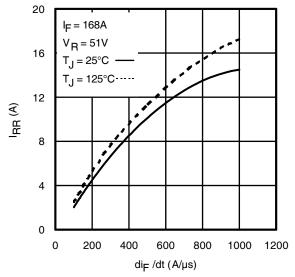


Fig. 18 - Typical Recovery Current vs. dif/dt

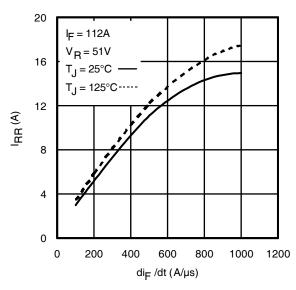


Fig. 17 - Typical Recovery Current vs. di_f/dt

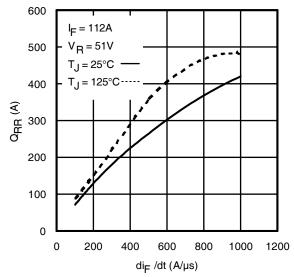


Fig. 19 - Typical Stored Charge vs. dif/dt

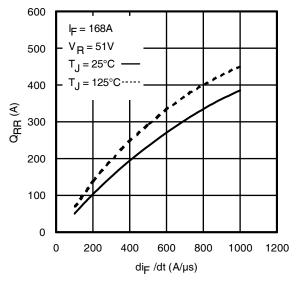


Fig. 20 - Typical Stored Charge vs. dif/dt

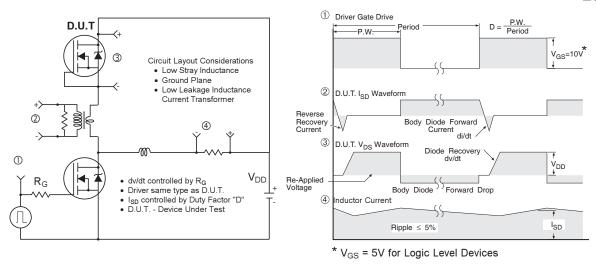


Fig 21. Peak Diode Recovery dv/dt Test Circuit for N-Channel HEXFET® Power MOSFETs

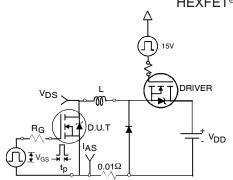


Fig 22a. Unclamped Inductive Test Circuit

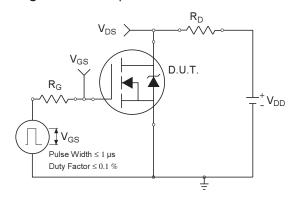


Fig 23a. Switching Time Test Circuit

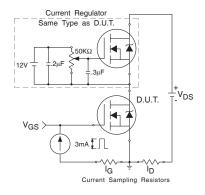


Fig 24a. Gate Charge Test Circuit

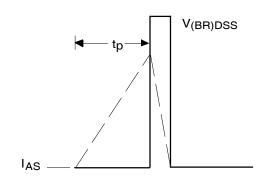


Fig 22b. Unclamped Inductive Waveforms

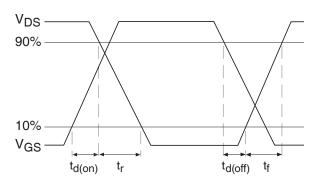


Fig 23b. Switching Time Waveforms

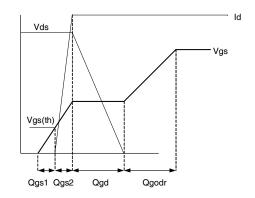
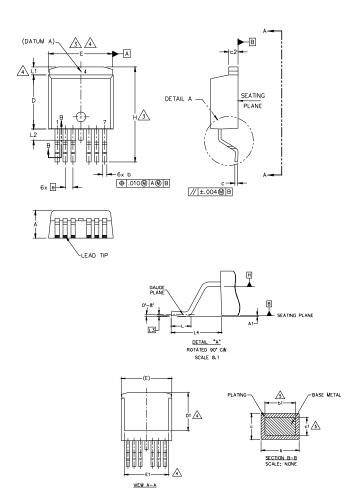


Fig 24b. Gate Charge Waveform

D²Pak (TO-263CB) 7 Long Leads Package Outline

Dimensions are shown in milimeters (inches)

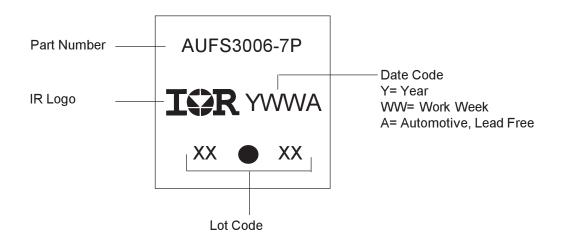


S Y M	DIMENSIONS				
Ιв	MILLIM	ETERS	INC	INCHES	
0 L	MIN.	MAX.	MIN.	MAX.	N O T E S
Α	4.06	4.83	.160	.190	
A1	_	0.254	_	.010	
b	0.51	0.99	.020	.036	
b1	0.51	0.89	.020	.032	5
С	0.38	0.74	.015	.029	
c1	0.38	0.58	.015	.023	5
c2	1.14	1.65	.045	.065	
D	8.38	9.65	.330	.380	3
D1	6.86	_	.270		4
E	9.65	10.67	.380	.420	3,4
E1	6.22	-	.245		4
е	1.27	BSC	.050	BSC	
Н	14.61	15.88	.575	.625	
L	1.78	2.79	.070	.110	
L1	_	1.68	_	.066	4
L2	_	1.78	_	.070	
L3	0.25	BSC	.010	.010 BSC	
L4	4.78	5.28	.188	.208	

NOTES:

- 1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M-1994
- 2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
- O.127 [.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY AT DATUM H.
- 4. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSION E, L1, D1 & E1.
- 5. DIMENSION 61 AND c1 APPLY TO BASE METAL ONLY.
- 6. DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 7. CONTROLLING DIMENSION: INCH.
- 8. OUTLINE CONFORMS TO JEDEC OUTLINE TO-263CB.

D²Pak - 7 Pin Part Marking Information



Note: For the most current drawing please refer to IR website at: http://www.irf.com/package/www.irf.com

D²Pak - 7 Pin Tape and Reel

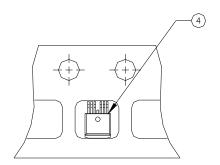
Dimensions are shown in milimeters (inches)

NOTES, TAPE & REEL, LABELLING:

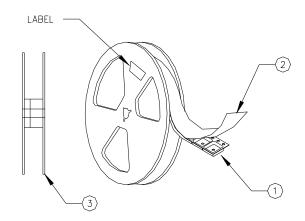
- 1. TAPE AND REEL.
 - 1.1 REEL SIZE 13 INCH DIAMETER.
 - 1.2 EACH REEL CONTAINING 800 DEVICES.
 - 1.3 THERE SHALL BE A MINIMUM OF 42 SEALED POCKETS CONTAINED IN THE LEADER AND A MINIMUM OF 15 SEALED POCKETS IN THE TRAILER.
 - 1.4 PEEL STRENGTH MUST CONFORM TO THE SPEC. NO. 71-9667.
 - 1.5 PART ORIENTATION SHALL BE AS SHOWN BELOW.
 - 1.6 REEL MAY CONTAIN A MAXIMUM OF TWO UNIQUE LOT CODE/DATE CODE COMBINATIONS.

 REWORKED REELS MAY CONTAIN A MAXIMUM OF THREE UNIQUE LOT CODE/DATE CODE COMBINATIONS.

 HOWEVER, THE LOT CODES AND DATE CODES WITH THEIR RESPECTIVE QUANTITIES SHALL APPEAR ON THE BAR CODE LABEL FOR THE AFFECTED REEL.



- 2. LABELLING (REEL AND SHIPPING BAG).
 - 2.1 CUST. PART NUMBER (BAR CODE): IRFXXXXSTRL-7P
 - 2.2 CUST. PART NUMBER (TEXT CODE): IRFXXXXSTRL-7P
 - 2.3 I.R. PART NUMBER: IRFXXXXSTRL-7P
 - 2.4 QUANTITY:
 - 2.5 VENDOR CODE: IR
 - 2.6 LOT CODE:
 - 2.7 DATE CODE:



Note: For the most current drawing please refer to IR website at: http://www.irf.com/package/

Ordering Information

Base part number	Package Type	Standard Pack		Standard Pack		Complete Part Number
		Form	Quantity			
AUIRFS3006-7P	D2Pak 7 Pin	Tube	50	AUIRFS3006-7P		
		Tape and Reel Left	800	AUIRFS3006-7TRR		
		Tape and Reel Right	800	AUIRFS3006-7TRL		

IMPORTANT NOTICE

Unless specifically designated for the automotive market, International Rectifier Corporation and its subsidiaries (IR) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or services without notice. Part numbers designated with the "AU" prefix follow automotive industry and/or customer specific requirements with regards to product discontinuance and process change notification. All products are sold subject to IR's terms and conditions of sale supplied at the time of order acknowledgment.

IR warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with IR's standard warranty. Testing and other quality control techniques are used to the extent IR deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

IR assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using IR components. To minimize the risks with customer products and applications, customers should provide adequate design and operating safeguards.

Reproduction of IR information in IR data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alterations is an unfair and deceptive business practice. IR is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of IR products or serviced with statements different from or beyond the parameters stated by IR for that product or service voids all express and any implied warranties for the associated IR product or service and is an unfair and deceptive business practice. IR is not responsible or liable for any such statements.

IR products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or in other applications intended to support or sustain life, or in any other application in which the failure of the IR product could create a situation where personal injury or death may occur. Should Buyer purchase or use IR products for any such unintended or unauthorized application, Buyer shall indemnify and hold International Rectifier and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that IR was negligent regarding the design or manufacture of the product.

Only products certified as military grade by the Defense Logistics Agency (DLA) of the US Department of Defense, are designed and manufactured to meet DLA military specifications required by certain military, aerospace or other applications. Buyers acknowledge and agree that any use of IR products not certified by DLA as military-grade, in applications requiring military grade products, is solely at the Buyer's own risk and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

IR products are neither designed nor intended for use in automotive applications or environments unless the specific IR products are designated by IR as compliant with ISO/TS 16949 requirements and bear a part number including the designation "AU". Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, IR will not be responsible for any failure to meet such requirements.

For technical support, please contact IR's Technical Assistance Center http://www.irf.com/technical-info/

 $\label{eq:world headquarters:} World \ \mbox{Headquarters:}$

101 N. Sepulveda Blvd., El Segundo, California 90245
 Tel: (310) 252-7105